NSN 5962-01-248-5010

Memory Microcircuit - Page 1 of 1



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Body Length:	
0.425 inches	
Body Width:	
0.290 inches	
Body Height:	
0.085 inches	
Maximum Power Diss	ipation Rating:
1.0 watts	
Operating Tempuratu	re Range:
-55.0/+125.0 degrees	zelsius
Storage Tempurature	Range:
-65.0/+150.0 degrees	zelsius
Features Provided:	
Electrostatic sensitive	and hermetically sealed and burn in and high reliability and monolithic
Inclosure Material:	
Ceramic	
Inclosure Configurati	on:
Leadless flat pack	
Output Logic Form:	
Complementary-metal	oxide-semiconductor logic
Input Circuit Pattern:	
17 input	
Terminal Surface Tre	atment:
Solder	
Voltage Rating And T	ype Per Characteristic:
7.0 volts power source	
Time Rating Per Chae	eteristic:
70.00 nanoseconds p	opagation delay time, low to high level output and 70.00 nanoseconds propagation delay time, high to low level
output	
Memory Device Type	
Ram	
Test Data Document:	
96906-mil-std-883 star	dard (includes industry or association standards, individual manufactureer standards, etc.).
Terminal Type And Q	uantity:
20 leadless	
Shelf Life:	
N/a	
Unit Of Measure:	
Demilitarization:	
Yes - demil/mli	
Fiig:	
A458a0	